

**Product data sheet** 

#### 1. General description

Planar passivated high commutation three quadrant triac in a IITO3P package intended for use in circuits where high static and dynamic dV/dt and high dI/dt can occur. This "series BT" triac will commutate the full RMS current at the maximum rated junction temperature ( $T_{j(max)} =$  150 °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

#### 2. Features and benefits

- High current TRIAC
- 3Q technology for improved noise immunity
- · High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- High junction operating temperature capability (T<sub>i(max)</sub> = 150 °C)
- High voltage capability
- Least sensitive gate for highest noise immunity
- Low thermal resistance
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only
- Insulated tab rated at 2500Vrms

#### 3. Applications

- Applications subject to high temperature (T<sub>i(max)</sub> = 150 °C)
- High current / high surge applications
- High power / industrial controls e.g. heating, motors, lighting

#### 4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 105 °C; <u>Fig. 1; Fig. 2</u> ; <u>Fig. 3</u>	-	-	45	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	450	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	-	495	А
Tj	junction temperature		-	-	150	°C

**3Q Hi-Com Triac** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G+};$ T <sub>j</sub> = 25 °C; Fig. 7	-	-	50	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T <sub>j</sub> = 25 °C; Fig. 7	-	-	50	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	80	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 63.6 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	1.7	V
Dynamic o	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	1000	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 20 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	15	-	-	A/ms

# 5. Pinning information

Table 2.	<b>Pinning infor</b>	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	$\bigcirc$	N
2	T2	main terminal 2	0	
3	G	gate		sym051
mb	n.c.	mounting base; isolated		
			IITO3P (SOT1292)	

# 6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	Name		method	quantity	version	issue date		
BTA445Z-800BT	IITO3P	BTA445Z-800BTQ	Tube	30	SOT1292	21-July-2017		

#### 7. Marking

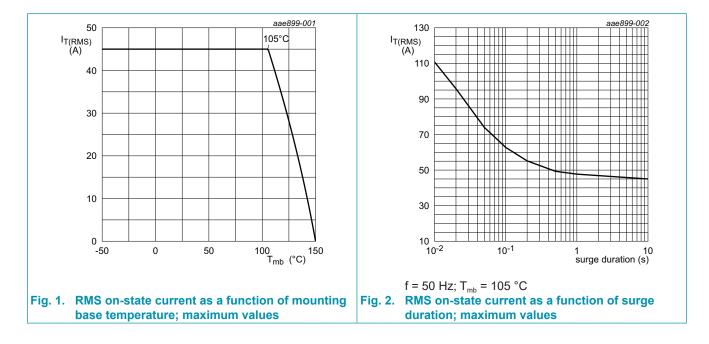
Table 4. Marking codes	
Type number	Marking code
BTA445Z-800BT	BTA445Z-800BT

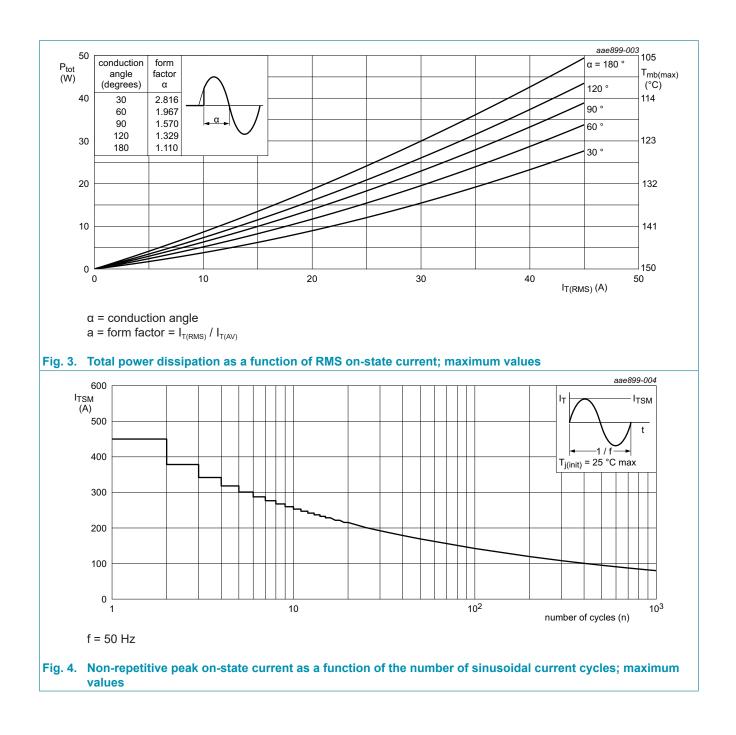
## 8. Limiting values

#### Table 5. Limiting values

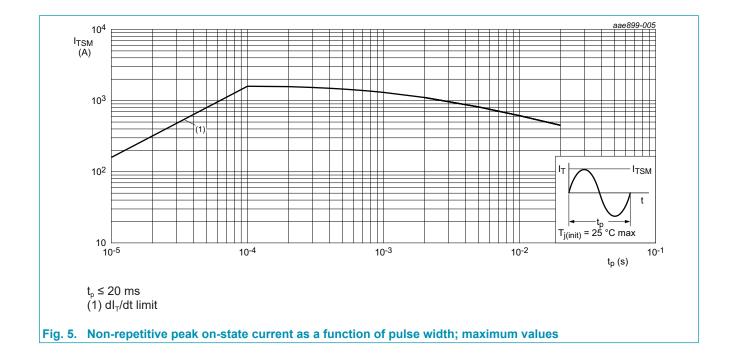
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	800	V
$\mathbf{I}_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 105 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	45	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig 4</u> ; <u>Fig 5</u>	-	450	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	495	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	-	1012.5	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 100 mA	-	150	A/µs
I <sub>GM</sub>	peak gate current	t <sub>p</sub> = 20 μs	-	8	А
$P_{GM}$	peak gate power	t <sub>p</sub> = 20 μs	-	40	W
$P_{\text{G}(\text{AV})}$	average gate power		-	1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C



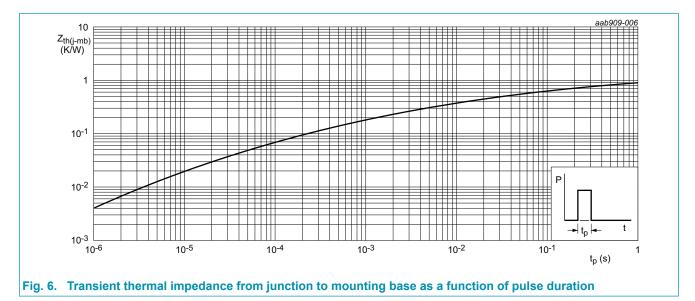


#### BTA445Z-800BT 3Q Hi-Com Triac



### 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig 6</u>	-	-	0.9	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W



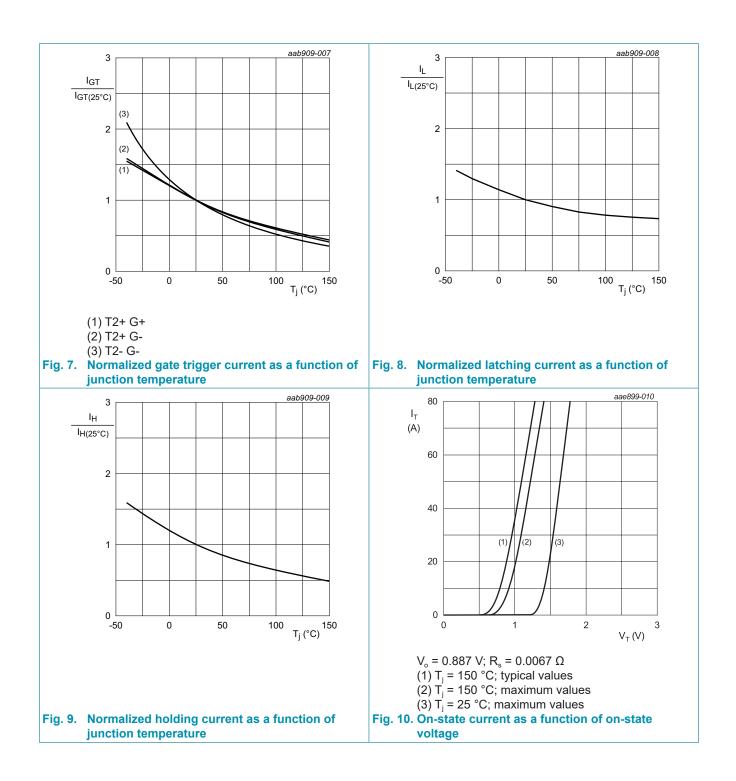
## **10. Isolation Characteristics**

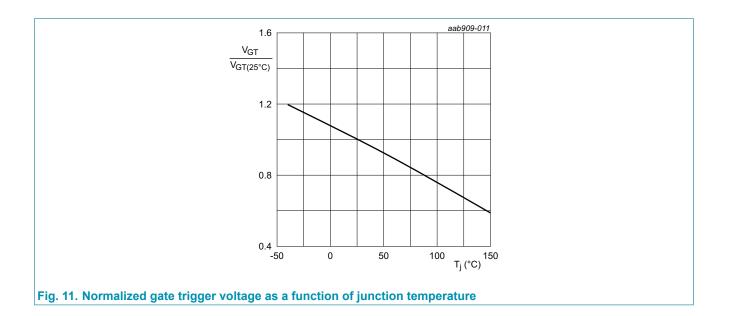
Table 7. Iso	plation Characteristics		 			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz $\leq$ f $\leq$ 60 Hz; RH $\leq$ 65 %; T <sub>mb</sub> = 25 °C	-	-	2500	V

### **11. Characteristics**

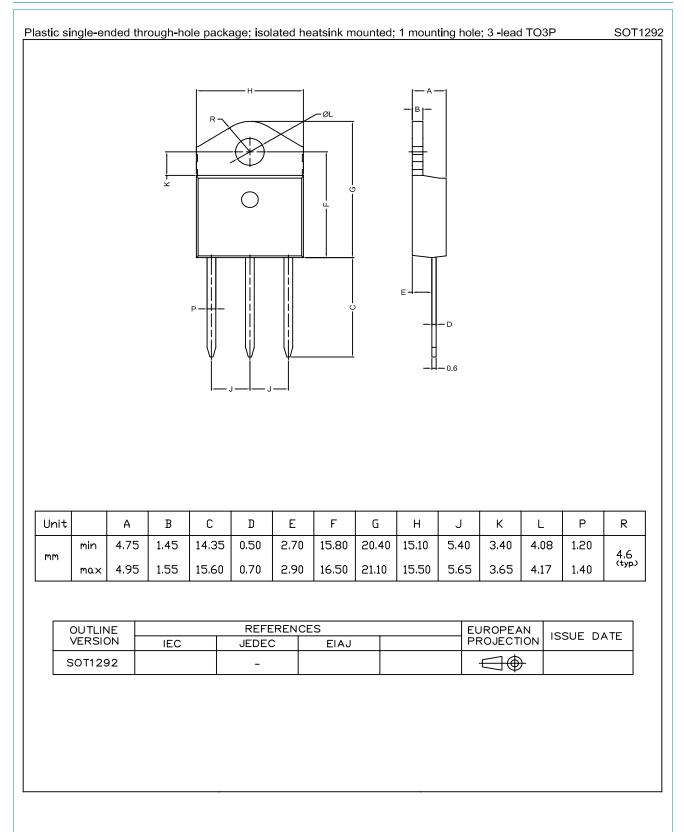
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	racteristics			- 71-		
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 7}$	-	-	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; Fig. 7	-	-	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T <sub>j</sub> = 25 °C; Fig. 7	-	-	50	mA
IL	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T <sub>j</sub> = 25 °C; Fig. 8	-	-	85	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; Fig. 8	-	-	160	mA
		$V_{D}$ = 12 V; I <sub>G</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; Fig. 8	-	-	85	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	80	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 63.6 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	1.7	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	0.8	1.3	V
		V <sub>D</sub> = 400 V; T <sub>j</sub> = 150 °C	0.2	0.45	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 800 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>D</sub> = 800 V; T <sub>j</sub> = 150 °C	-	-	2	mA
Dynamic	characteristics	· · · · ·	I	_		_
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	1000	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 20 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit}$	15	-	-	A/ms

BTA445Z-800BT 3Q Hi-Com Triac





### 12. Package outline



#### BTA445Z-800BT 3Q Hi-Com Triac

## 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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# BTA445Z-800BT

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